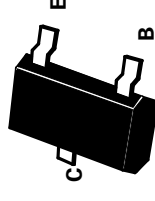


# SOT23 PNP SILICON PLANAR MEDIUM POWER SWITCHING TRANSISTORS

## BSS69 BSS70

ISSUE 2 – SEPTEMBER 1995

PARTMARKING DETAILS — BSS69 - L2  
BSS70 - L3  
BSS69R - L6  
BSS70R - L7



### ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	VALUE	UNIT
Collector-Base Voltage	$V_{CBO}$	-40	V
Collector-Emitter Voltage	$V_{CEO}$	-40	V
Emitter-Base Voltage	$V_{EBO}$	-5	V
Peak Pulse Current	$I_{CM}$	-200	mA
Continuous Collector Current	$I_C$	-100	mA
Base Current	$I_B$	-50	mA
Power Dissipation at $T_{amb}=25^{\circ}C$	$P_{TOT}$	330	mW
Operating and Storage Temperature Range	$t_j; t_{stg}$	-55 to +150	$^{\circ}C$

### ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}C$ ).

PARAMETER	SYMBOL	MIN.	MAX.	UNIT	CONDITIONS.
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	-40		V	$I_C = -1mA$
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-40		V	$I_C = -10\mu A$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-5		V	$I_E = -10\mu A$
Collector - Emitter Cut-off Current	$I_{CES}$		-50	nA	$V_{CES} = -30V$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$		-0.25 -0.40	V	$I_C = -10mA, I_B = -1mA$ $I_C = -50mA, I_B = -5mA^*$
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	-0.65	-0.85 -0.95	V	$I_C = -10mA, I_B = -1mA$ $I_C = -50mA, I_B = -5mA^*$
Static Forward Current Transfer Ratio	$h_{FE}$	30 40 50 30 15			$I_C = -100\mu A,$ $I_C = -1mA,$ $I_C = -10mA, V_{CE} = -1V$ $I_C = -50mA^*,$ $I_C = -100mA^*,$
Static Forward Current Transfer Ratio	$h_{FE}$	60 80 100 60 30			$I_C = -100\mu A,$ $I_C = -1mA,$ $I_C = -10mA, V_{CE} = -1V$ $I_C = -50mA^*,$ $I_C = -100mA^*,$
Transition Frequency	$f_T$	200 250		MHz	$I_C = -10mA, V_{CE} = -20V$ $f = 100MHz$
Collector-Base Capacitance	$C_{ob0}$		4.5	pF	$V_{CB} = -5V, f = 100kHz$
Emitter-Base Capacitance	$C_{ib0}$		10	pF	$V_{EB} = -0.5V, f = 100kHz$
Noise Figure	N	Typ. 5		dB	$I_C = -100\mu A, V_{CE} = -5V$ $R_S = 1k\Omega, f = 10Hz$ to 15.7 kHz
Switching times: Delay; Rise	$t_{d}; t_r$		35	ns	$V_{CC} = -3V, I_C = -10mA$
Storage Time	$t_s$		225	ns	$I_{B1} = I_{B2} = -1mA$
Fall Time	$t_f$		70	ns	

\*Measured under pulsed conditions. Pulse width=300 $\mu s$ . Duty cycle  $\leq 2\%$